CPH6347

Power MOSFET
–20V, 39mΩ, –6A, Single P-Channel

ON Semiconductor®

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V_{DSS}	$R_{DS(on)}$ Max	I_D Max
–20V	39mΩ@ –4.5V	–6A
	66mΩ@ –2.5V	
	102mΩ@ –1.8V	

Features

- Low Gate Drive Voltage
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS Compliance

Specifications

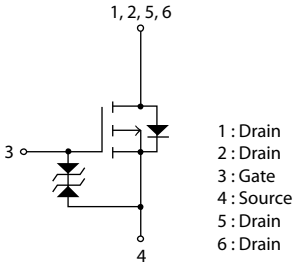
Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Value	Unit
Drain to Source Voltage	V_{DSS}	–20	V
Gate to Source Voltage	V_{GSS}	±12	V
Drain Current (DC)	I_D	–6	A
Drain Current (Pulse) PW≤10μs, duty cycle≤1%	I_{DP}	–24	A
Power Dissipation When mounted on ceramic substrate (900mm^2× 0.8mm)	P_D	1.6	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	–55 to +150	°C

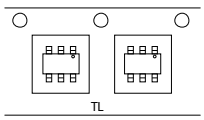
Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm^2× 0.8mm)	$R_{\theta JA}$	78.1	°C/W

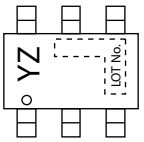
Electrical Connection
P-Channel



Packing Type : TL



Marking



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION
See detailed ordering and shipping information on page 5 of this data sheet.

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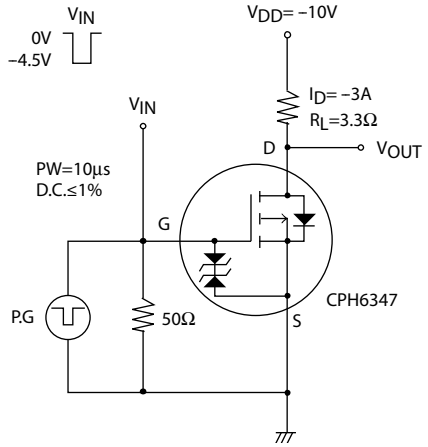
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Electrical Characteristics at Ta = 25°C

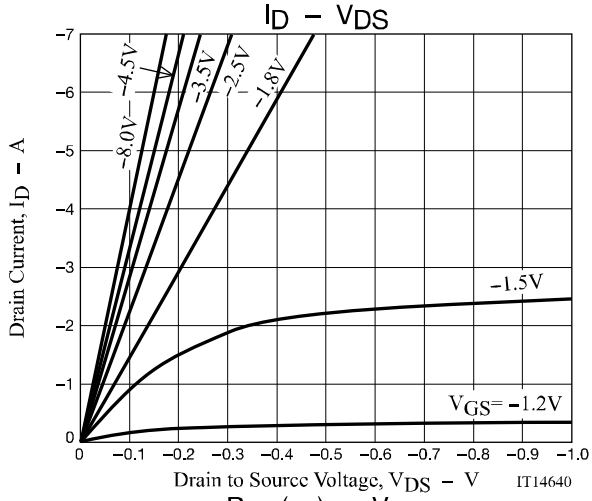
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	I_D=–1mA, V_{GS}=0V	–20			V
Zero-Gate Voltage Drain Current	I_{DSS}	V_{DS}=–20V, V_{GS}=0V			–1	μA
Gate to Source Leakage Current	I_{GSS}	V_{GS}=±8V, V_{DS}=0V			±10	μA
Gate Threshold Voltage	$V_{GS}(th)$	V_{DS}=–10V, I_D=–1mA	–0.4		–1.4	V
Forward Transconductance	g_{FS}	V_{DS}=–10V, I_D=–3A	4.3	7.3		S
Static Drain to Source On-State Resistance	$R_{DS}(on)1$	I_D=–3A, V_{GS}=–4.5V		30	39	mΩ
	$R_{DS}(on)2$	I_D=–1.5A, V_{GS}=–2.5V		44	66	mΩ
	$R_{DS}(on)3$	I_D=–0.6A, V_{GS}=–1.8V		68	102	mΩ
Input Capacitance	Ciss	V_{DS}=–10V, f=1MHz		860		pF
Output Capacitance	Coss			170		pF
Reverse Transfer Capacitance	Crss			130		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit		10		ns
Rise Time	t_r			48		ns
Turn-OFF Delay Time	$t_d(off)$			100		ns
Fall Time	t_f			78		ns
Total Gate Charge	Qg	V_{DS}=–10V, V_{GS}=–4.5V, I_D=–6A		10.5		nC
Gate to Source Charge	Qgs			2.0		nC
Gate to Drain “Miller” Charge	Qgd			3.0		nC
Forward Diode Voltage	V_{SD}	I_S=–6A, V_{GS}=0V		–0.82	–1.5	V

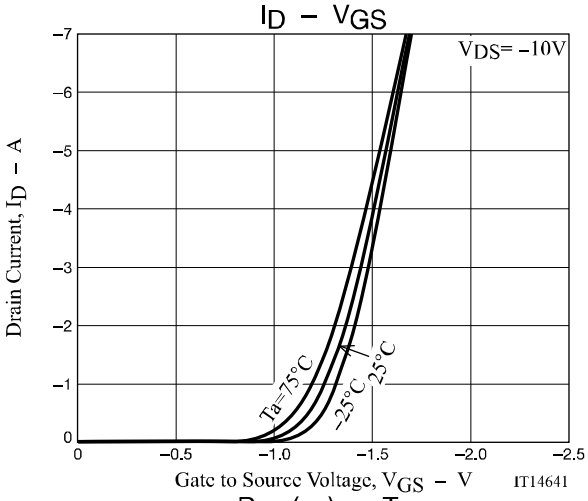
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

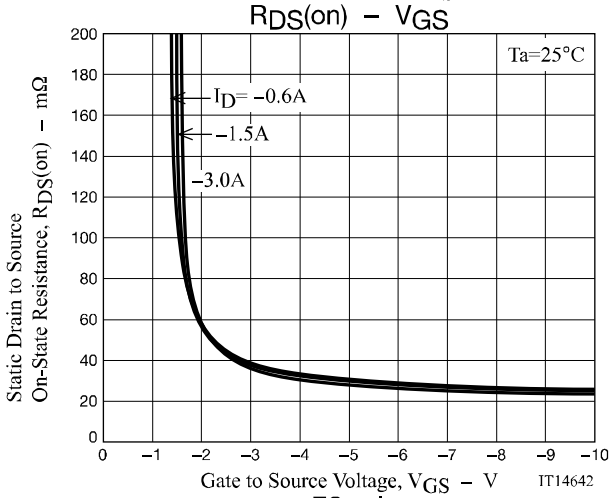
Switching Time Test Circuit

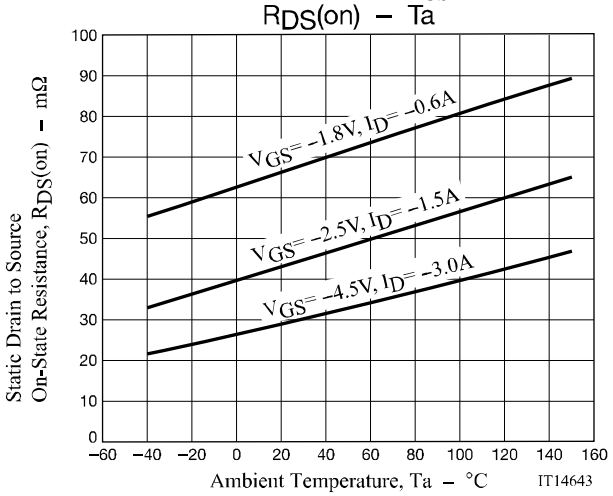


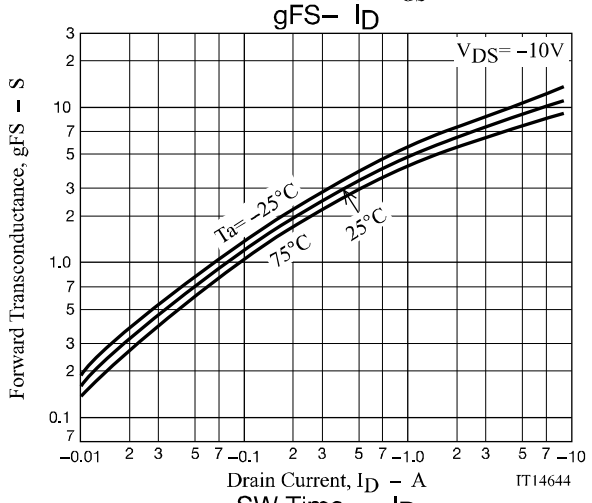
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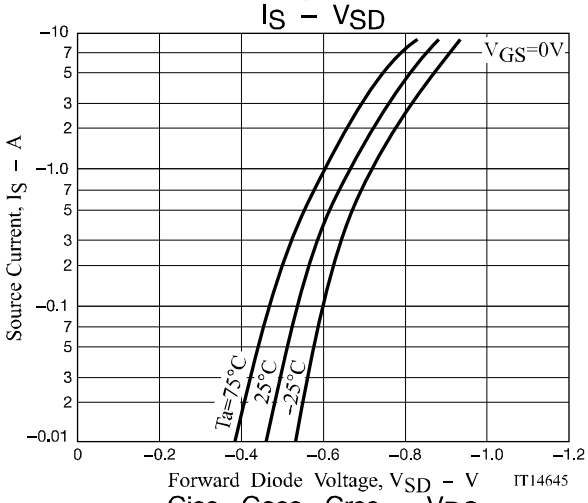


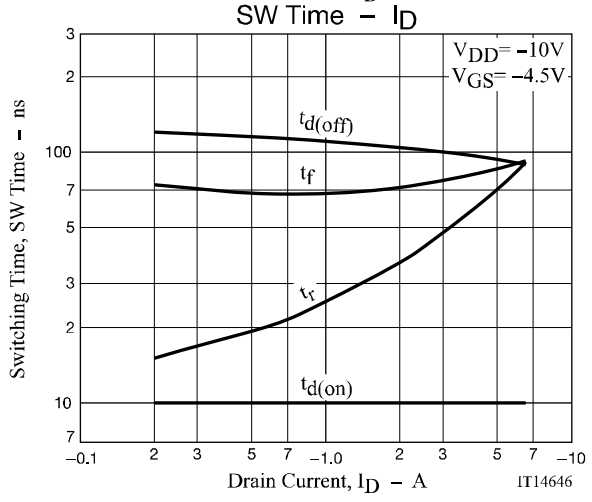


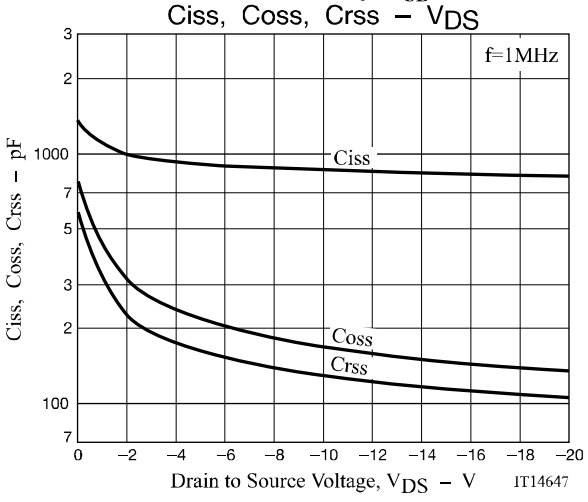




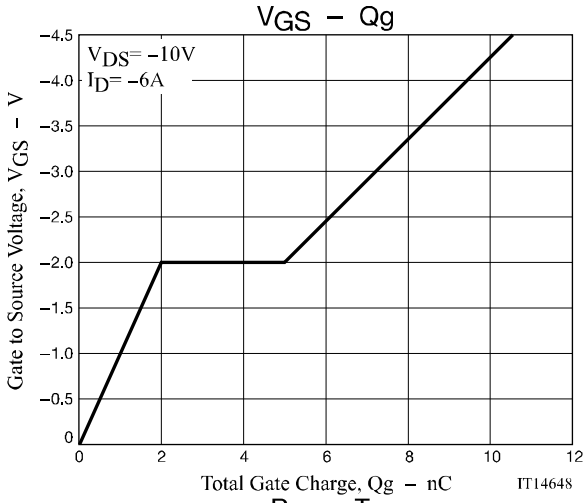


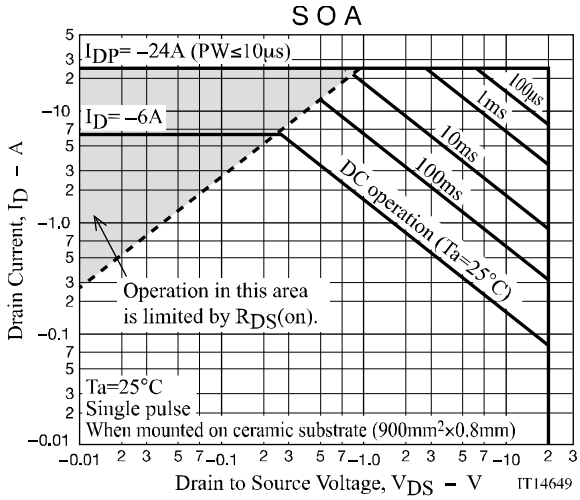


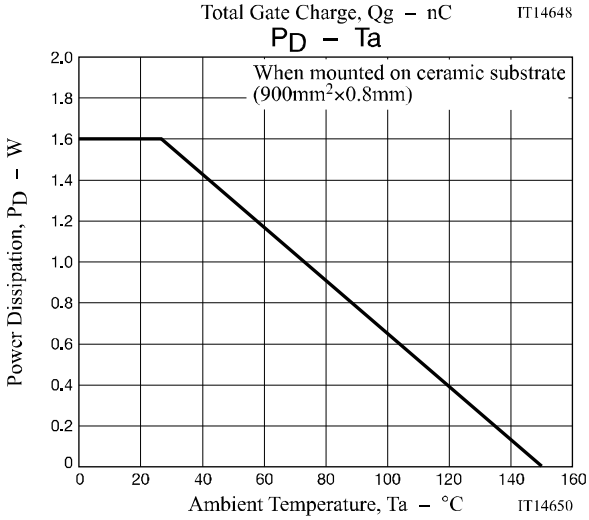


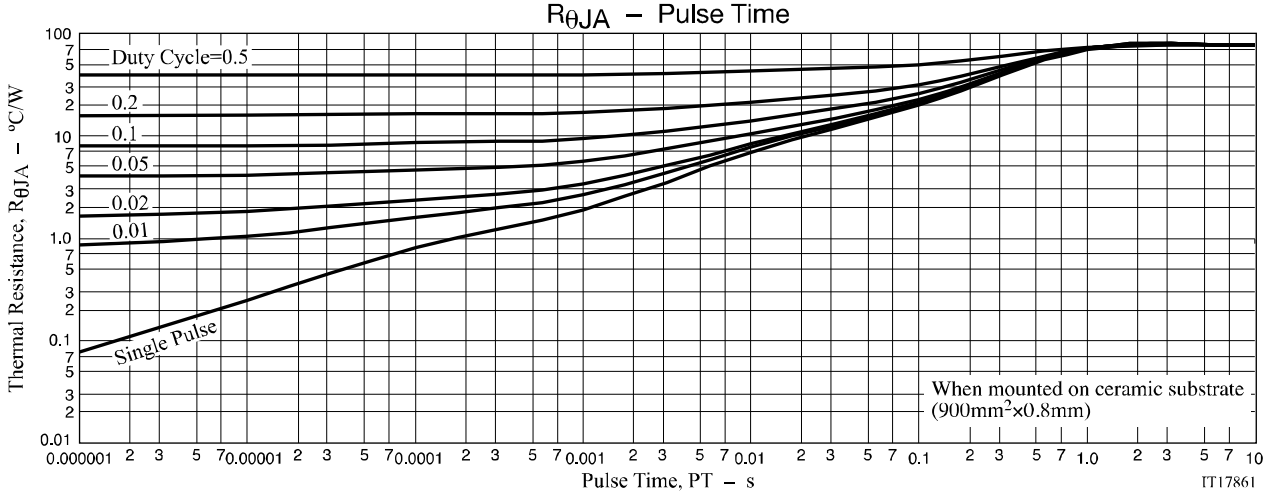


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Package Dimensions

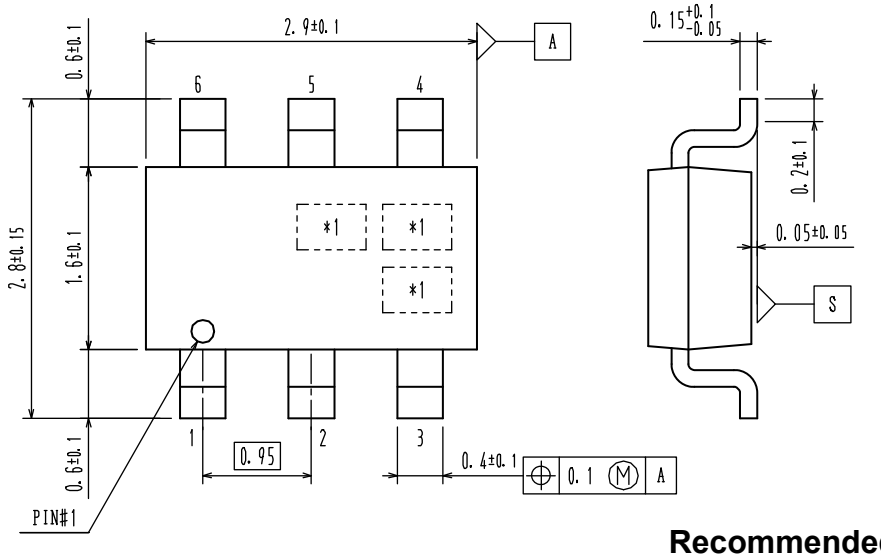
CPH6347-TL-H / CPH6347-TL-W

CPH6

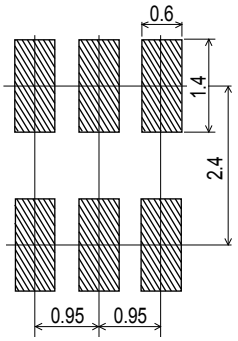
CASE 318BD
ISSUE O

Unit : mm

1 : Drain
2 : Drain
3 : Gate
4 : Source
5 : Drain
6 : Drain



Recommended Soldering Footprint



ORDERING INFORMATION

Device	Package	Shipping	Note
CPH6347-TL-H	CPH6 SC-74,SOT-26,SOT-457	3,000 pcs. / Tape & Reel	Pb-Free and Halogen Free
CPH6347-TL-W			

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the CPH6347 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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